

IPP410N30NAKSA1

IPP410N30NAKSA1 Information

www.heiseger.com	Manufacturer Category	IPP410N30NAKSA1 Infineon Technologies Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single	
	Description	MOSFET N-CH TO220-3	222200
	Package	TO-220-3	一台設支援
		For the pricing/inventory/lead time, please contact	
		us	
For Reference Only		Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote



Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



IPP410N30NAKSA1 Specifications

Manufacturer Part Number	IPP410N30NAKSA1
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-220-3
Series	OptiMOS?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	300V
Current - Continuous Drain (Id) @ 25°C	44A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	4V @ 270µA
Gate Charge (Qg) (Max) @ Vgs	87nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	7180pF @ 100V
Vgs (Max)	$\pm 20 V$
FET Feature	-
Power Dissipation (Max)	300W (Tc)
Rds On (Max) @ Id, Vgs	41 mOhm @ 44A, 10V
Operating Temperature	-55°C ~ 175°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	PG-TO-220-3
Package / Case	TO-220-3
	Report errors?

IPP410N30NAKSA1 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

IPP410N30NAKSA1 Payment Methods



IPP410N30NAKSA1 Shipping Methods



If you have any question about IPP410N30NAKSA1, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com